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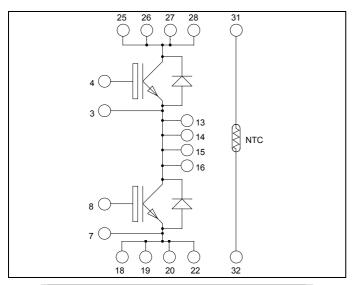


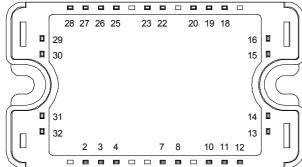


Phase leg NPT IGBT Power Module

$$V_{CES} = 1200V$$

 $I_{C} = 150A$ @ $Tc = 80$ °C





Pins 25/26/27/28 must be shorted together Pins 13/14/15/16 must be shorted together Pins 18/19/20/22 must be shorted together

Application

• Welding converters

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
- High level of integration
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Easy paralleling due to positive T_C of V_{CEsat}
- RoHS compliant

Absolute maximum ratings

11000141	·			
Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
ī	Continuous Collector Current	$T_C = 25^{\circ}C$	210	
I_{C}	Continuous Conector Current	$T_C = 80$ °C	150	Α
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	300	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25^{\circ}C$	961	W
RBSOA	Reverse Bias Safe Operating Area	$T_J = 150$ °C	300A @ 1150V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

www.microsemi.com

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All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				250	μΑ
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		3.2	3.7	V
$V_{CE(sat)}$	Conector Emitter Saturation Voltage	$I_{\rm C} = 150 {\rm A}$	$T_j = 125$ °C		3.9		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 6mA$		4.5	5.5	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE}$	$V_{GE} = 20V, V_{CE} = 0V$			400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Condition	Test Conditions		Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			9.3		
Coes	Output Capacitance				1.4		nF
C_{res}	Reverse Transfer Capacitance	f = 1MHz	f = 1MHz				
Q_{G}	Gate charge	$V_{GE} = \pm 15V ; V$ $I_{C} = 150A$	$V_{GE} = \pm 15V ; V_{CE} = 600V$ $I_{C} = 150A$		1.6		μС
$T_{d(on)}$	Turn-on Delay Time		Inductive Switching (25°C)				
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			50		ns
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600V$ $I_{\text{C}} = 150A$			310		
$T_{\rm f}$	Fall Time	$R_G = 5.6\Omega$	_				
$T_{d(on)}$	Turn-on Delay Time		Inductive Switching (125°C)				
$T_{\rm r}$	Rise Time		$V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 150A$ $R_{G} = 5.6\Omega$		60		ns
$T_{d(off)}$	Turn-off Delay Time				360		
T_{f}	Fall Time	$R_G = 5.6\Omega$			30		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		18		Т
E_{off}	Turn-off Switching Energy	$I_C = 150A$ $R_G = 5.6\Omega$	$T_j = 125$ °C		8		mJ
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; V_B $t_p \le 10 \mu s$; $T_i =$			900		A

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_j = 25$ °C			100	۸
1 _{RM}	Waximum Reverse Leakage Current	V _R −1200 V	$T_{j} = 125^{\circ}C$			500	μA
I_F	DC Forward Current		$Tc = 80^{\circ}C$		100		A
	Diode Forward Voltage	$I_{\rm F} = 100 A$			2.4	3	
V_{F}		$I_F = 200A$	r = 200A		2.7		V
		$I_F = 100A$	$T_j = 125$ °C		1.8		
t_{rr}	Reverse Recovery Time	$I_F = 100A$ - $V_R = 800V$	$T_j = 25$ °C		385		ns
· rr			$T_{\rm j} = 125^{\circ}{\rm C}$		480		115
Q _{rr}	Reverse Recovery Charge	$di/dt = 200A/\mu s$	$T_j = 25$ °C		1055	·	nC
			$T_{j} = 125^{\circ}C$		5240		110



 $Temperature\ sensor\ NTC\ (\text{see application note APT0406 on www.microsemi.com for more information}).$

Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta B/B$		T _C =100°C		4		%

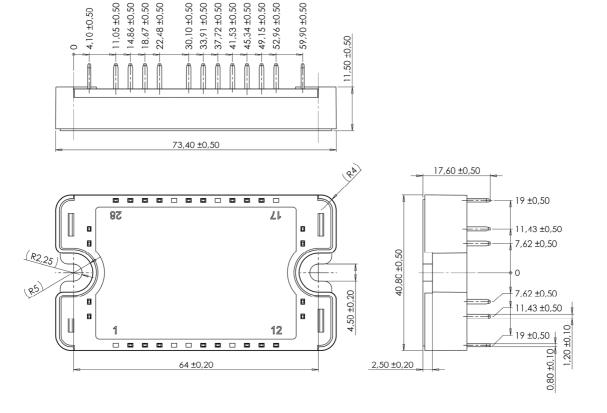
$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{ Thermistor value at T}$$

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case thermal resistance		IGBT			0.13	°C/W
KthJC			Diode			0.55	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					110	g

SP3 Package outline (dimensions in mm)

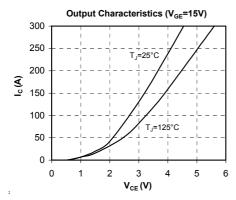


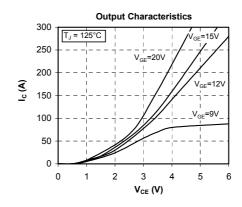
See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

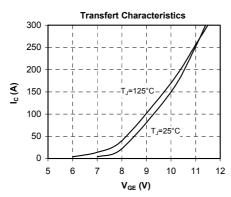
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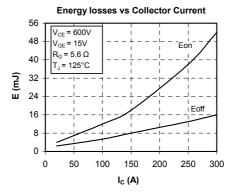


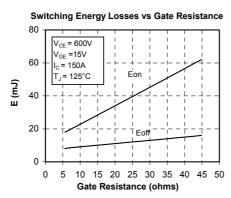
Typical Performance Curve

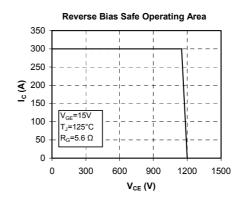


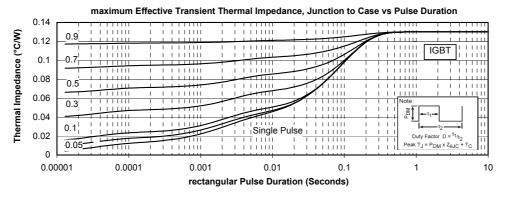




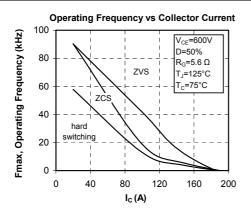


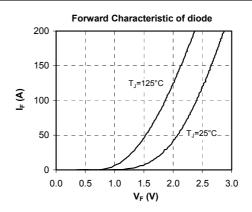


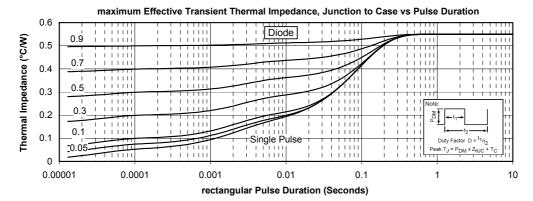












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